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Nature of Quality Factor Degradation in SRF Cavities due to Quench

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Introduction

- Q₀ degradation due to quench in bulk niobium cavities attributed to trapped magnetic flux¹.
- Where does this flux come from?
 - Thermocurrents at the quench spot¹
 - Trapped RF field
 - Ambient field²
- We have proved that the Q₀ quench-related degradation mechanism is due only to the trapping of ambient magnetic field.

¹ J. Knobloch, H. Padamsee, *Proceedings of the 8th Workshop on RF Superconductivity*, Abano Terme, Italy (1997) ² I.M. Terechkine *et al.*, *Proceedings of 13th International Conference on RF Superconductivity*, Paris, France (2013)



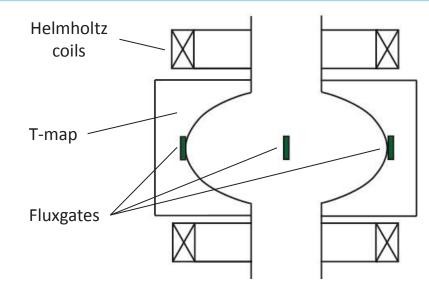
Experimental Set-up & Procedure

<u>Set-up:</u>

- Helmholtz coils
- 4 Fluxgates magnetometers
- T-map system

Procedure:

- 1. $Q_0 vs E_{acc}$ before any quench
- 2. Cavity quench with RF field
 - i. Different values of external magnetic field
 - ii. Field compensation till H < 1 mOe
- 3. Q_0 and T-map measured after the quench



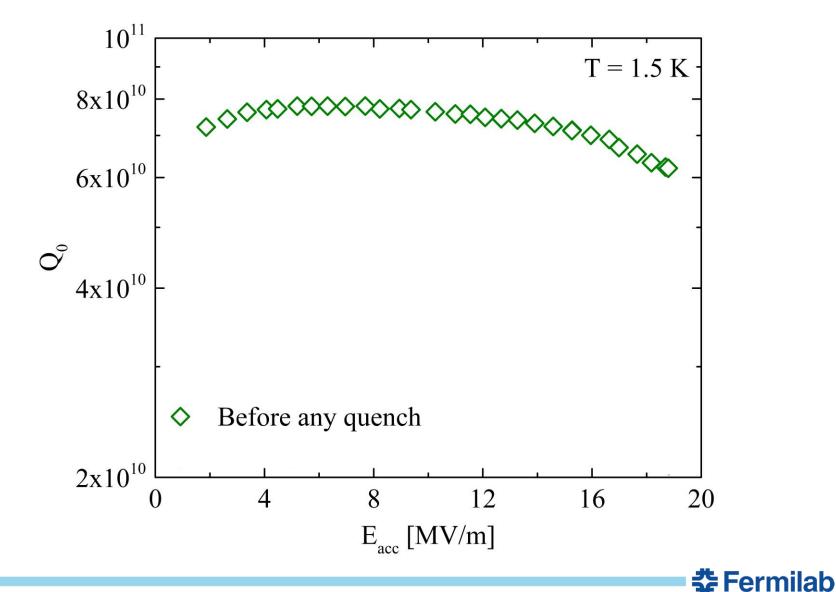




Q₀ recovery and origin of trapped magnetic flux



Q_0 vs E_{acc} before any quench



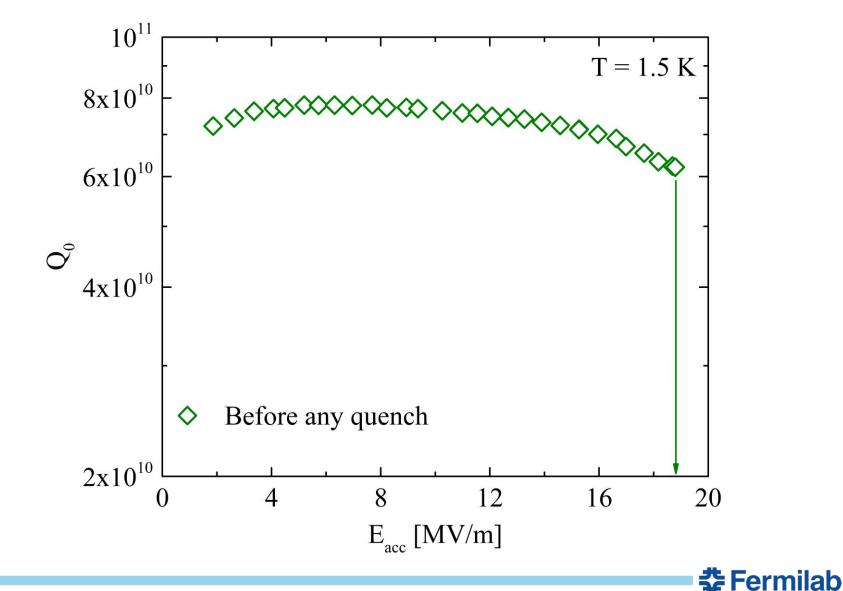
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Cavity quench with RF field



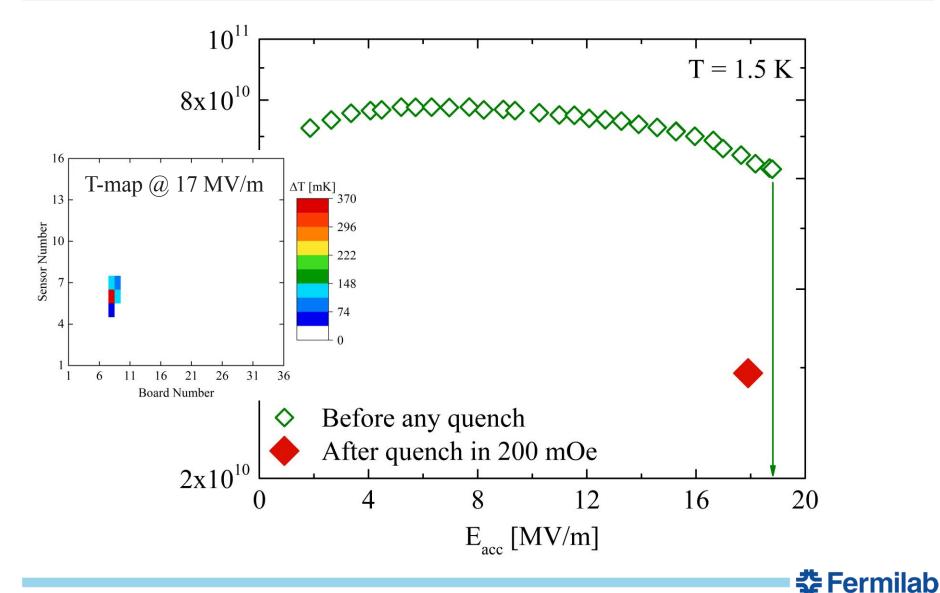
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Quench in 200 mOe



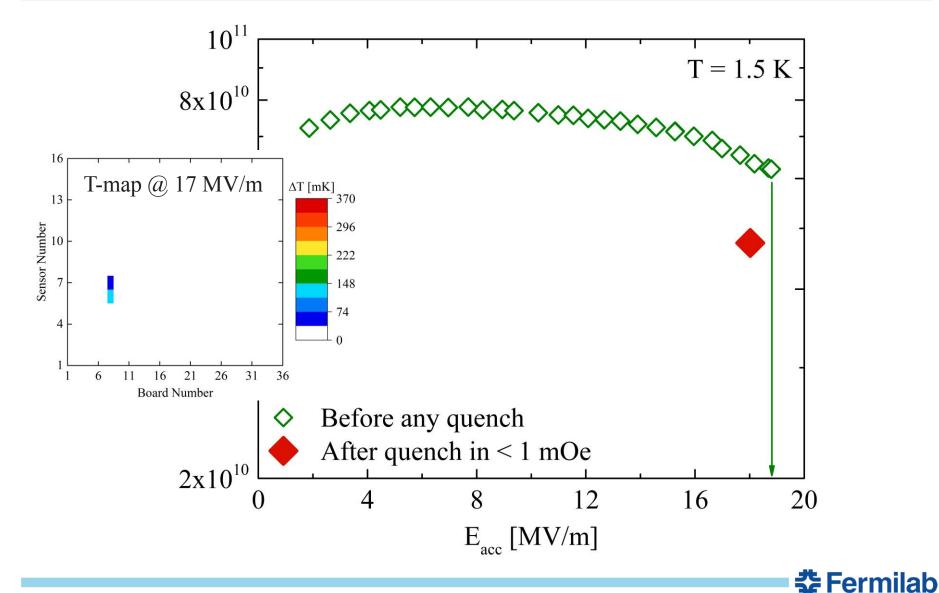
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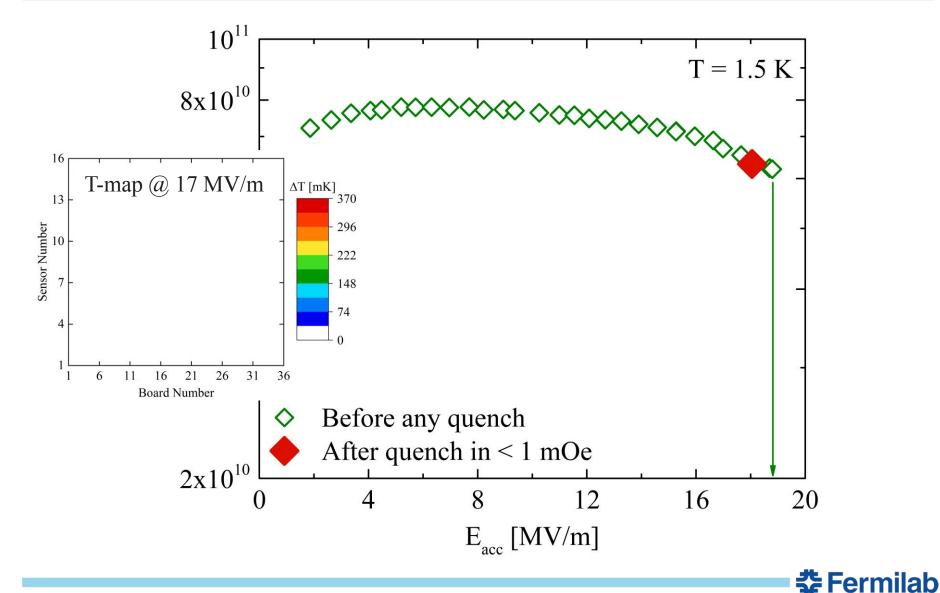
Quench in < 1 mOe



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Quench in < 1 mOe



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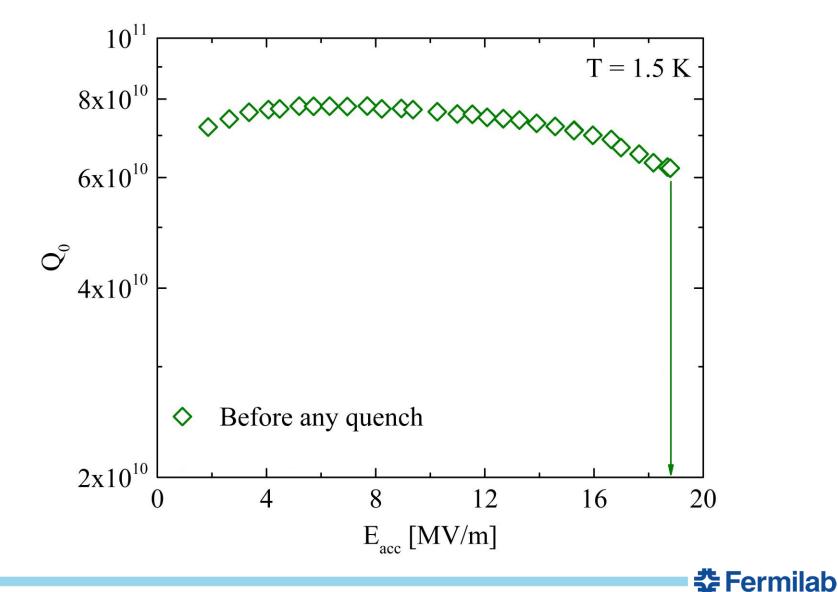
Complete Q₀ Recovery!

Without warming above T_c

 \rightarrow First hint on the extrinsic origin of flux trapping



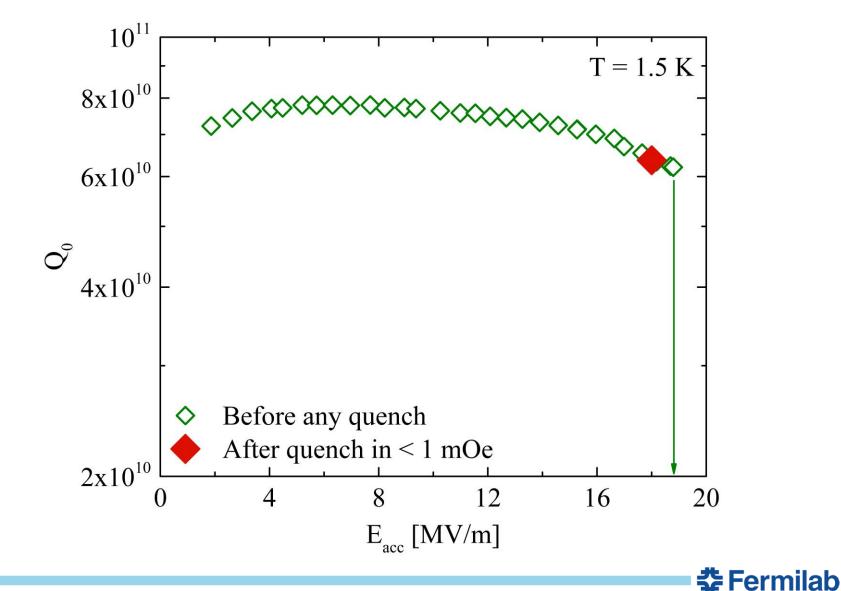
Q_0 vs E_{acc} before any quench



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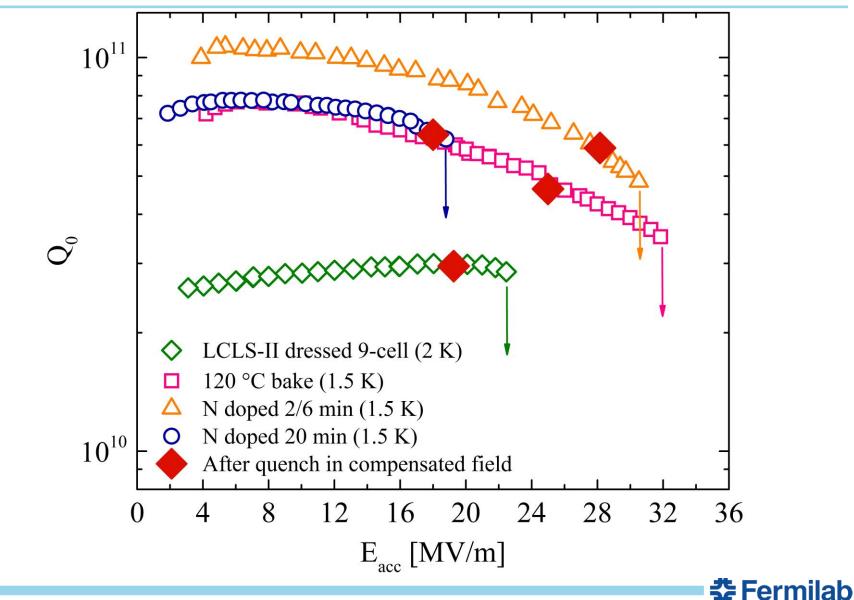
Quench in < 1 mOe



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Quench in < 1 mOe for different treatments



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No degradation quenching in < 1 mOe

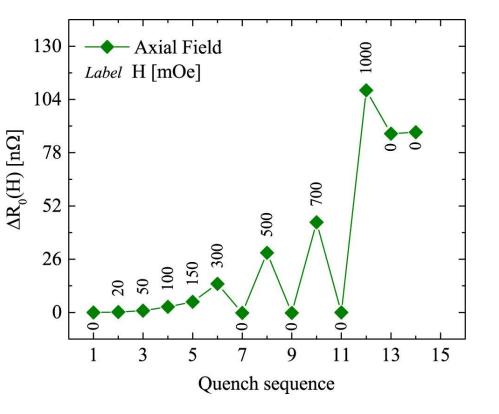
No Q₀ Degradation!

Flux trapping is an <u>extrinsic</u> phenomenon <u>only</u>!

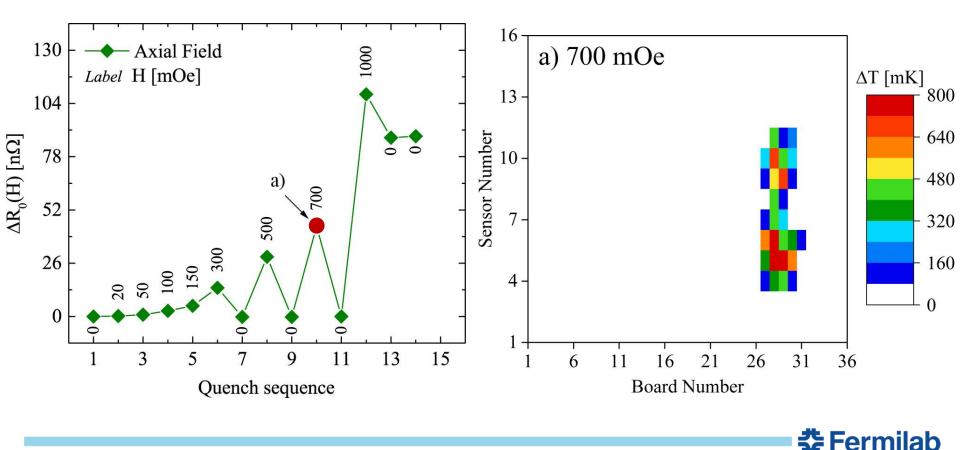


Is Q₀ always totally recoverable?



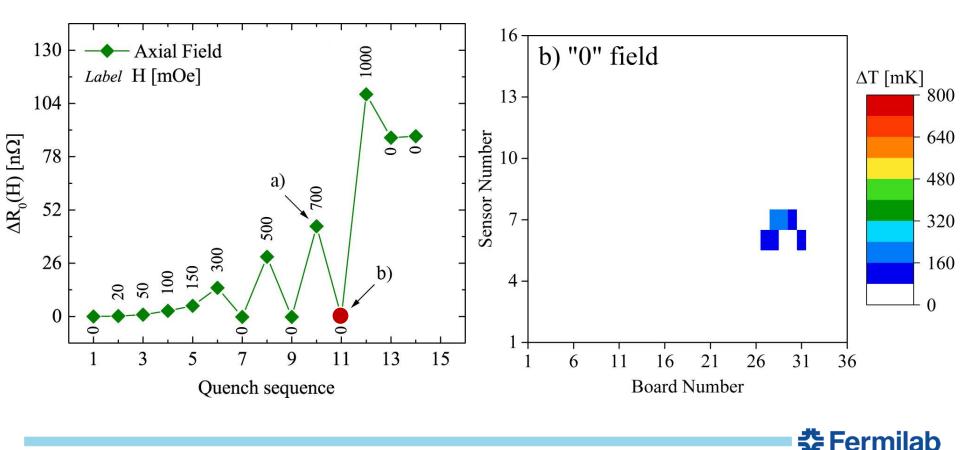






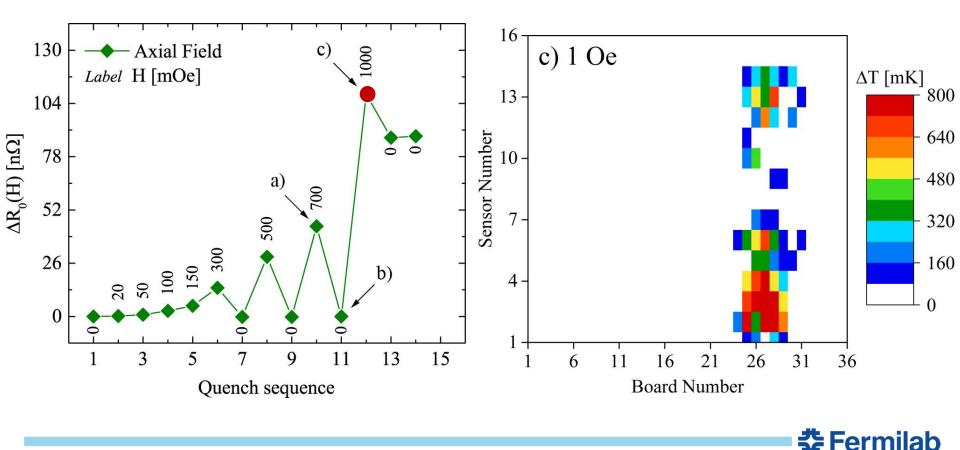
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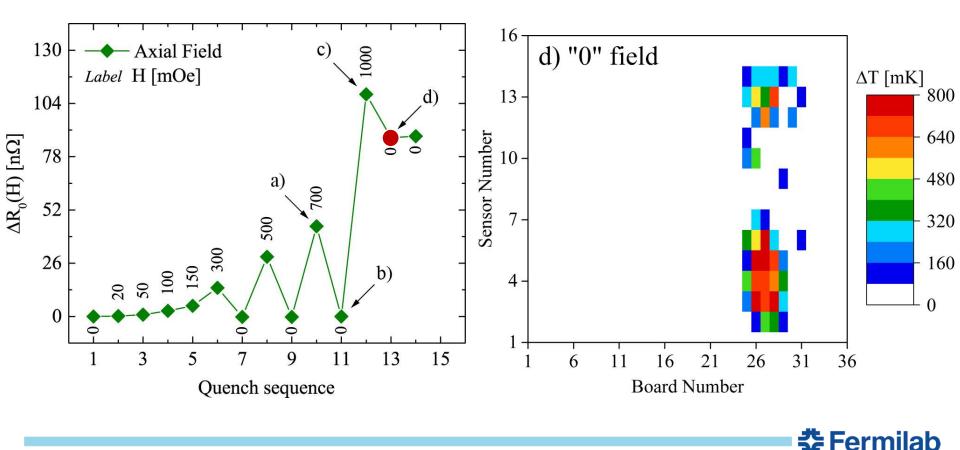
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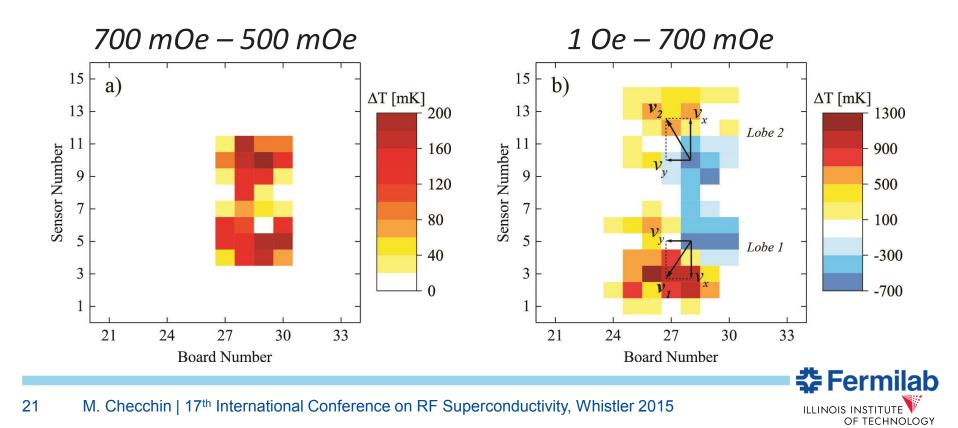


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The flux migrates driven by its own thermal gradient

$$-S\nabla T - \eta \bar{v} - f n_s e(\bar{v} \times \phi_0 \hat{n}) - \bar{f_p} = 0$$



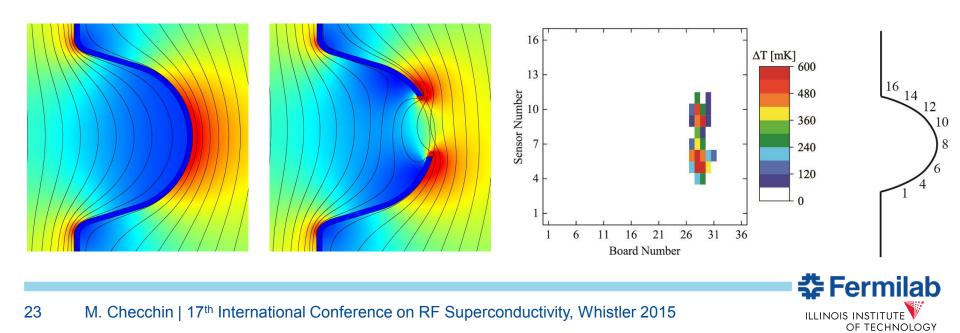
How is the flux trapped?



Magnetic flux trapping dynamics

How the magnetic flux is trapped? It creates a semi-loop at the quench spot

Why the magnetic flux is not expelled? Hypothesis: field redistribution time constant > than cooling time constant



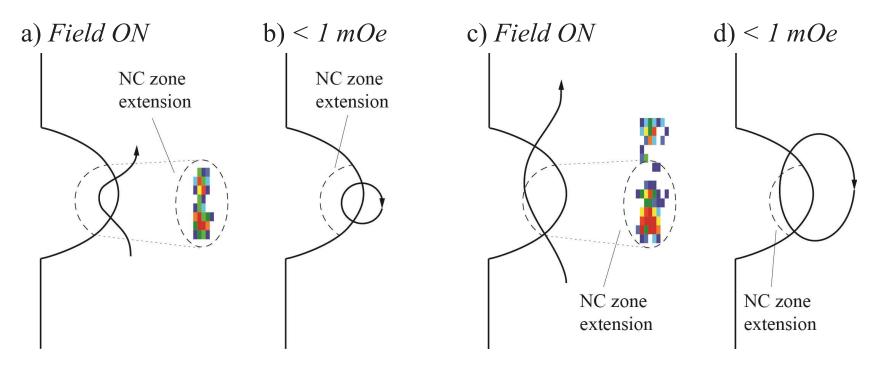
How does the recovery work?



How does the Q₀ recovery work?

Magnetic field exists only if currents are present

$$\oint \overline{B} \cdot d\overline{l} = \mu_0 I$$





Conclusions

First time demonstration: Q₀ degradation due to quench is related to ambient field only

- I. No Q_0 degradation when quenching in < 1 mOe
- II. Total recovery of Q_0 achieved when quenching in < 1 mOe

Above an external field threshold Q₀ cannot be recovered anymore

I. Trapped field can migrate driven by its local thermal gradient



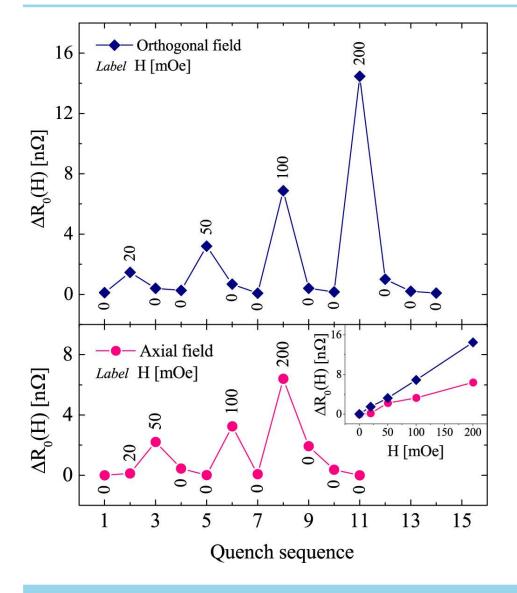
Thank you

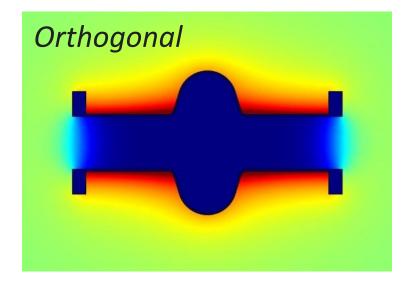


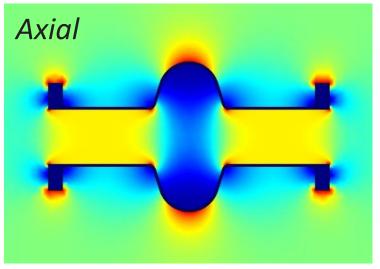
Back-up Slides



External field orientation dependence

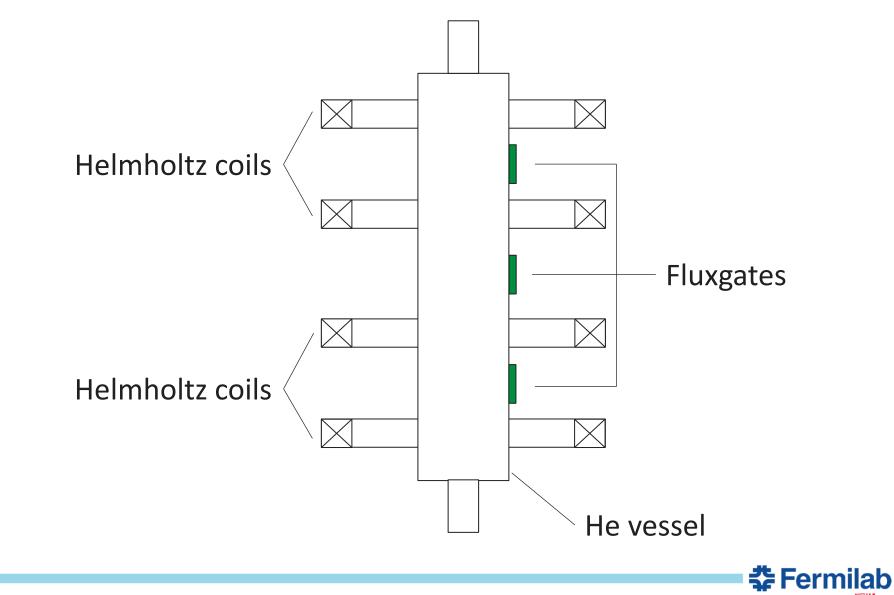








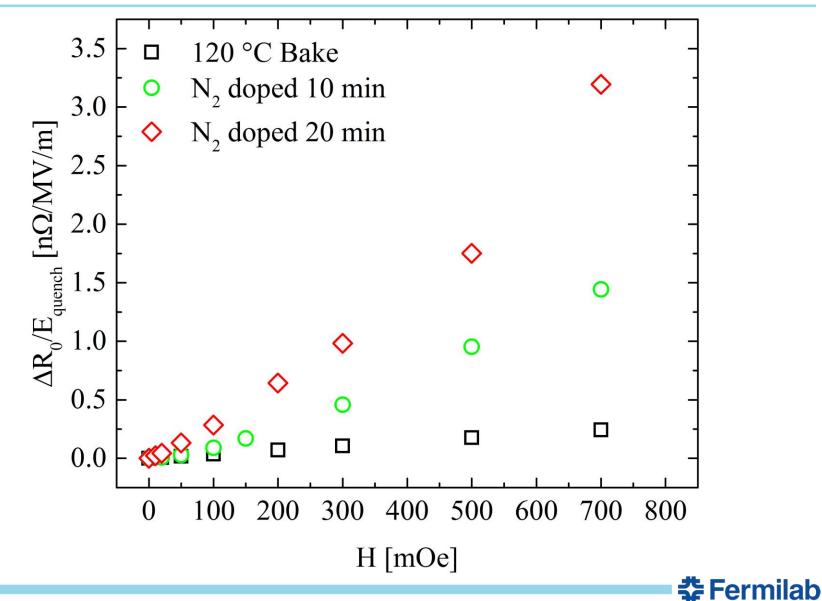
Dressed 9-cell set-up



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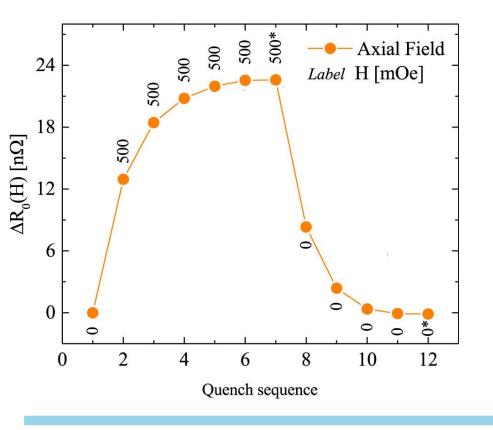
Dissipation comparison



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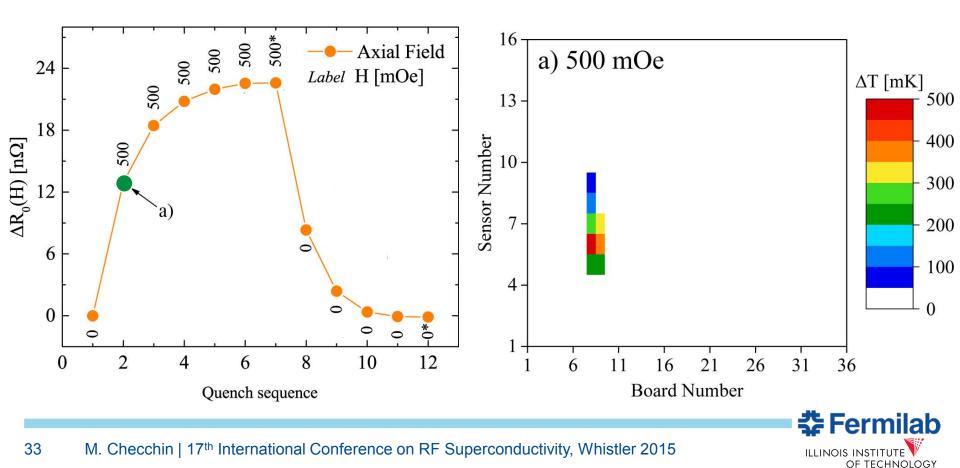
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- I. Every quench depletes the local applied field at the quench spot
- II. The extra surface resistance saturates

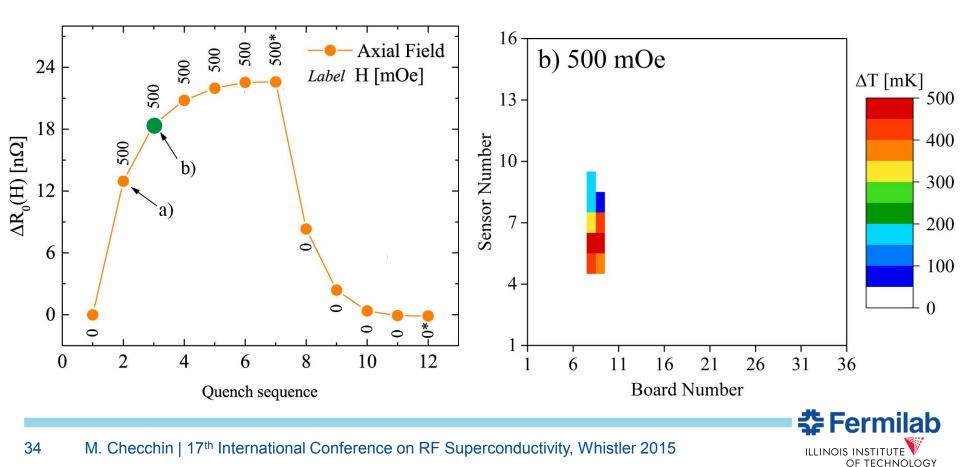




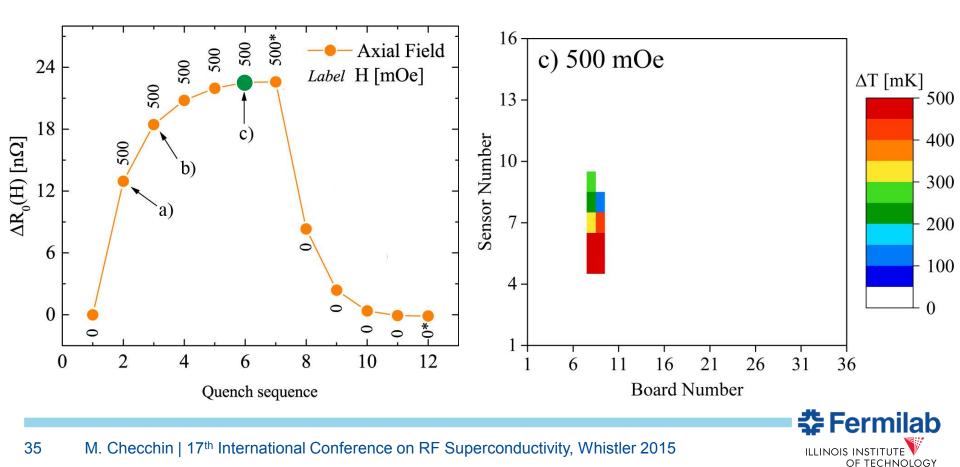
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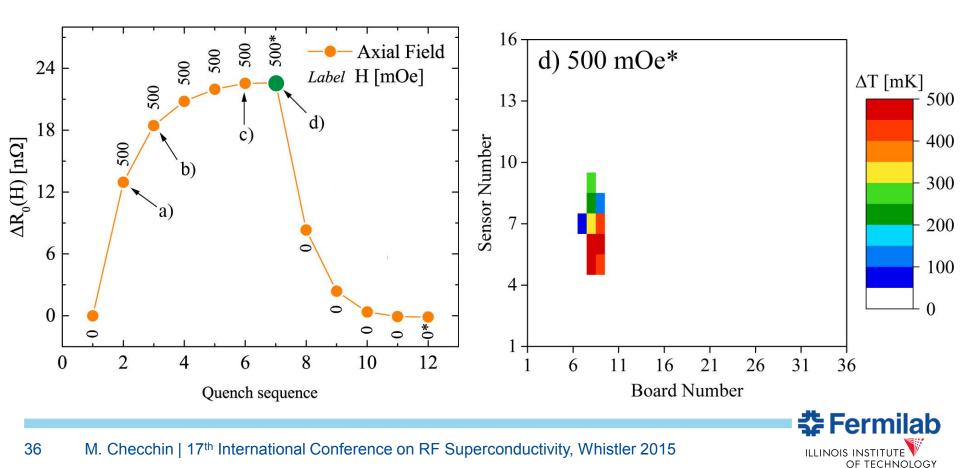
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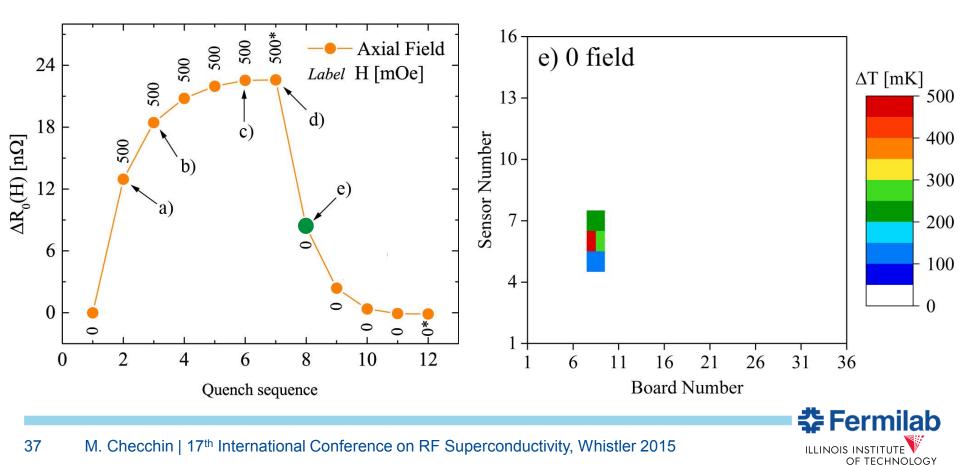
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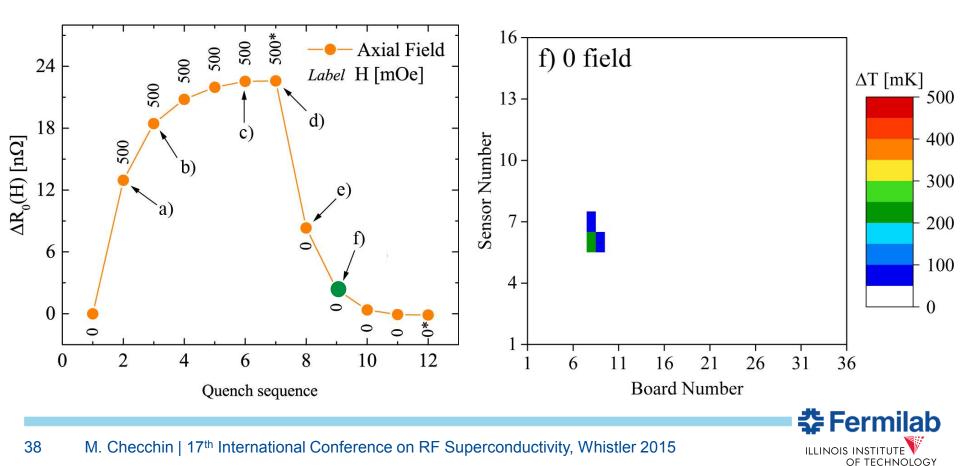
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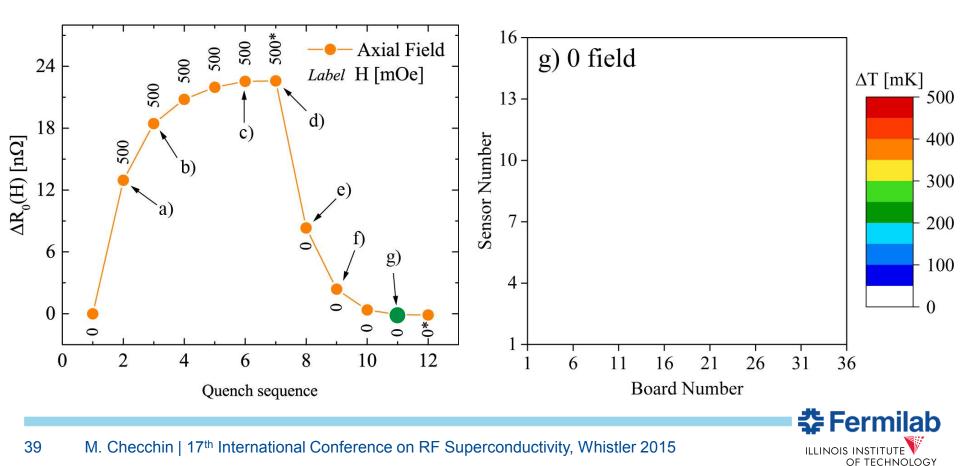
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- II. Several quenches in applied field < 1 mOe are needed



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